

# Dual PNP Bias Resistor Transistors

**R1 = 47 kΩ, R2 = 47 kΩ**

## PNP Transistors with Monolithic Bias Resistor Network

### MUN5113DW1, NSBA144EDXV6, NSBA144EDP6

This series of digital transistors is designed to replace a single device and its external resistor bias network. The Bias Resistor Transistor (BRT) contains a single transistor with a monolithic bias network consisting of two resistors; a series base resistor and a base-emitter resistor. The BRT eliminates these individual components by integrating them into a single device. The use of a BRT can reduce both system cost and board space.

#### Features

- Simplifies Circuit Design
- Reduces Board Space
- Reduces Component Count
- S and NSV Prefix for Automotive and Other Applications Requiring Unique Site and Control Change Requirements; AEC-Q101 Qualified and PPAP Capable\*
- These Devices are Pb-Free, Halogen Free/BFR Free and are RoHS Compliant

#### MAXIMUM RATINGS

(T<sub>A</sub> = 25°C, common for Q1 and Q2, unless otherwise noted)

| Symbol               | Rating                         | Max | Unit |
|----------------------|--------------------------------|-----|------|
| V <sub>CB0</sub>     | Collector-Base Voltage         | 50  | Vdc  |
| V <sub>CEO</sub>     | Collector-Emitter Voltage      | 50  | Vdc  |
| I <sub>C</sub>       | Collector Current - Continuous | 100 | mAdc |
| V <sub>IN(fwd)</sub> | Input Forward Voltage          | 40  | Vdc  |
| V <sub>IN(rev)</sub> | Input Reverse Voltage          | 10  | Vdc  |

Stresses exceeding those listed in the Maximum Ratings table may damage the device. If any of these limits are exceeded, device functionality should not be assumed, damage may occur and reliability may be affected.



SOT-363  
CASE 419B

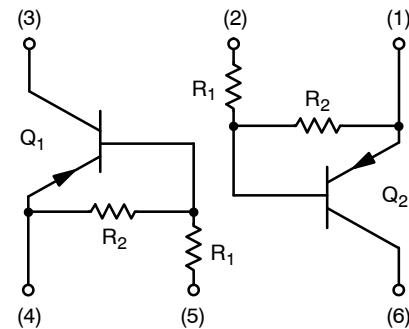


SOT-563  
CASE 463A

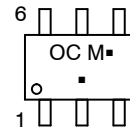


SOT-963  
CASE 527AD

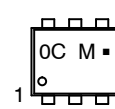
#### PIN CONNECTIONS



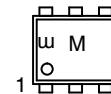
#### MARKING DIAGRAMS



SOT-363  
CASE 419B



SOT-563  
CASE 463A



SOT-963  
CASE 527AD

OC/m = Specific Device Code  
M = Date Code\*  
▪ = Pb-Free Package

(Note: Microdot may be in either location)

\*Date Code orientation may vary depending upon manufacturing location.

#### ORDERING INFORMATION

See detailed ordering, marking and shipping information in the package dimensions section on page 6 of this data sheet.

NOTE: Some of the devices on this data sheet have been **DISCONTINUED**. Please refer to the table on page 6.

# MUN5113DW1, NSBA144EDXV6, NSBA144EDP6

## THERMAL CHARACTERISTICS

| Symbol | Characteristic | Max | Unit |
|--------|----------------|-----|------|
|--------|----------------|-----|------|

### MUN5113DW1 (SOT-363) One Junction Heated

|                 |                                                                 |                   |                      |
|-----------------|-----------------------------------------------------------------|-------------------|----------------------|
| $P_D$           | Total Device Dissipation<br>$T_A = 25^\circ\text{C}$ (Note 1)   | 187               | mW                   |
|                 | (Note 2)<br>Derate above $25^\circ\text{C}$ (Note 1)            | 256<br>1.5<br>2.0 | mW/ $^\circ\text{C}$ |
| $R_{\theta JA}$ | Thermal Resistance,<br>Junction to Ambient (Note 1)<br>(Note 2) | 670<br>490        | $^\circ\text{C/W}$   |

### MUN5113DW1 (SOT-363) Both Junction Heated (Note 3)

|                 |                                                                 |                   |                      |
|-----------------|-----------------------------------------------------------------|-------------------|----------------------|
| $P_D$           | Total Device Dissipation<br>$T_A = 25^\circ\text{C}$ (Note 1)   | 250               | mW                   |
|                 | (Note 2)<br>Derate above $25^\circ\text{C}$ (Note 1)            | 385<br>2.0<br>3.0 | mW/ $^\circ\text{C}$ |
| $R_{\theta JA}$ | Thermal Resistance,<br>Junction to Ambient (Note 1)<br>(Note 2) | 493<br>325        | $^\circ\text{C/W}$   |
| $R_{\theta JL}$ | Thermal Resistance,<br>Junction to Lead (Note 1)<br>(Note 2)    | 188<br>208        | $^\circ\text{C/W}$   |
| $T_J, T_{stg}$  | Junction and Storage Temperature Range                          | -55 to +150       | $^\circ\text{C}$     |

### NSBA144EDXV6 (SOT-563) One Junction Heated

|                 |                                                               |     |                      |
|-----------------|---------------------------------------------------------------|-----|----------------------|
| $P_D$           | Total Device Dissipation<br>$T_A = 25^\circ\text{C}$ (Note 1) | 357 | mW                   |
|                 | Derate above $25^\circ\text{C}$ (Note 1)                      | 2.9 | mW/ $^\circ\text{C}$ |
| $R_{\theta JA}$ | Thermal Resistance,<br>Junction to Ambient (Note 1)           | 350 | $^\circ\text{C/W}$   |

### NSBA144EDXV6 (SOT-563) Both Junction Heated (Note 3)

|                 |                                                               |             |                      |
|-----------------|---------------------------------------------------------------|-------------|----------------------|
| $P_D$           | Total Device Dissipation<br>$T_A = 25^\circ\text{C}$ (Note 1) | 500         | mW                   |
|                 | Derate above $25^\circ\text{C}$ (Note 1)                      | 4.0         | mW/ $^\circ\text{C}$ |
| $R_{\theta JA}$ | Thermal Resistance,<br>Junction to Ambient (Note 1)           | 250         | $^\circ\text{C/W}$   |
| $T_J, T_{stg}$  | Junction and Storage Temperature Range                        | -55 to +150 | $^\circ\text{C}$     |

### NSBA144EDP6 (SOT-963) One Junction Heated

|                 |                                                                 |                   |                      |
|-----------------|-----------------------------------------------------------------|-------------------|----------------------|
| $P_D$           | Total Device Dissipation<br>$T_A = 25^\circ\text{C}$ (Note 4)   | 231               | mW                   |
|                 | (Note 5)<br>Derate above $25^\circ\text{C}$ (Note 4)            | 269<br>1.9<br>2.2 | mW/ $^\circ\text{C}$ |
| $R_{\theta JA}$ | Thermal Resistance,<br>Junction to Ambient (Note 4)<br>(Note 5) | 540<br>464        | $^\circ\text{C/W}$   |

### NSBA144EDP6 (SOT-963) Both Junction Heated (Note 3)

|                 |                                                                 |                   |                      |
|-----------------|-----------------------------------------------------------------|-------------------|----------------------|
| $P_D$           | Total Device Dissipation<br>$T_A = 25^\circ\text{C}$ (Note 4)   | 339               | mW                   |
|                 | (Note 5)<br>Derate above $25^\circ\text{C}$ (Note 4)            | 408<br>2.7<br>3.3 | mW/ $^\circ\text{C}$ |
| $R_{\theta JA}$ | Thermal Resistance,<br>Junction to Ambient (Note 4)<br>(Note 5) | 369<br>306        | $^\circ\text{C/W}$   |
| $T_J, T_{stg}$  | Junction and Storage Temperature Range                          | -55 to +150       | $^\circ\text{C}$     |

- FR-4 @ Minimum Pad.
- FR-4 @ 1.0 x 1.0 Inch Pad.
- Both junction heated values assume total power is sum of two equally powered channels.
- FR-4 @ 100 mm<sup>2</sup>, 1 oz. copper traces, still air.
- FR-4 @ 500 mm<sup>2</sup>, 1 oz. copper traces, still air.

# MUN5113DW1, NSBA144EDXV6, NSBA144EDP6

## ELECTRICAL CHARACTERISTICS ( $T_A = 25^\circ\text{C}$ , common for Q<sub>1</sub> and Q<sub>2</sub>, unless otherwise noted)

| Symbol | Characteristic | Min | Typ | Max | Unit |
|--------|----------------|-----|-----|-----|------|
|--------|----------------|-----|-----|-----|------|

### OFF CHARACTERISTICS

|               |                                                                                       |    |   |     |      |
|---------------|---------------------------------------------------------------------------------------|----|---|-----|------|
| $I_{CBO}$     | Collector-Base Cutoff Current<br>( $V_{CB} = 50\text{ V}$ , $I_E = 0$ )               | –  | – | 100 | nAdc |
| $I_{CEO}$     | Collector-Emitter Cutoff Current<br>( $V_{CE} = 50\text{ V}$ , $I_B = 0$ )            | –  | – | 500 | nAdc |
| $I_{EBO}$     | Emitter-Base Cutoff Current<br>( $V_{EB} = 6.0\text{ V}$ , $I_C = 0$ )                | –  | – | 0.1 | mAdc |
| $V_{(BR)CBO}$ | Collector-Base Breakdown Voltage<br>( $I_C = 10\text{ }\mu\text{A}$ , $I_E = 0$ )     | 50 | – | –   | Vdc  |
| $V_{(BR)CEO}$ | Collector-Emitter Breakdown Voltage (Note 6)<br>( $I_C = 2.0\text{ mA}$ , $I_B = 0$ ) | 50 | – | –   | Vdc  |

### ON CHARACTERISTICS

|               |                                                                                                         |      |     |      |            |
|---------------|---------------------------------------------------------------------------------------------------------|------|-----|------|------------|
| $h_{FE}$      | DC Current Gain (Note 6)<br>( $I_C = 5.0\text{ mA}$ , $V_{CE} = 10\text{ V}$ )                          | 80   | 140 | –    |            |
| $V_{CE(sat)}$ | Collector-Emitter Saturation Voltage (Note 6)<br>( $I_C = 10\text{ mA}$ , $I_B = 0.3\text{ mA}$ )       | –    | –   | 0.25 | Vdc        |
| $V_{i(off)}$  | Input Voltage (off)<br>( $V_{CE} = 5.0\text{ V}$ , $I_C = 100\text{ }\mu\text{A}$ )                     | –    | 1.2 | –    | Vdc        |
| $V_{i(on)}$   | Input Voltage (on)<br>( $V_{CE} = 0.2\text{ V}$ , $I_C = 3.0\text{ mA}$ )                               | –    | 2.0 | –    | Vdc        |
| $V_{OL}$      | Output Voltage (on)<br>( $V_{CC} = 5.0\text{ V}$ , $V_B = 3.5\text{ V}$ , $R_L = 1.0\text{ k}\Omega$ )  | –    | –   | 0.2  | Vdc        |
| $V_{OH}$      | Output Voltage (off)<br>( $V_{CC} = 5.0\text{ V}$ , $V_B = 0.5\text{ V}$ , $R_L = 1.0\text{ k}\Omega$ ) | 4.9  | –   | –    | Vdc        |
| $R_1$         | Input Resistor                                                                                          | 32.9 | 47  | 61.1 | k $\Omega$ |
| $R_1/R_2$     | Resistor Ratio                                                                                          | 0.8  | 1.0 | 1.2  |            |

6. Pulsed Condition: Pulse Width = 300 msec, Duty Cycle  $\leq 2\%$ .

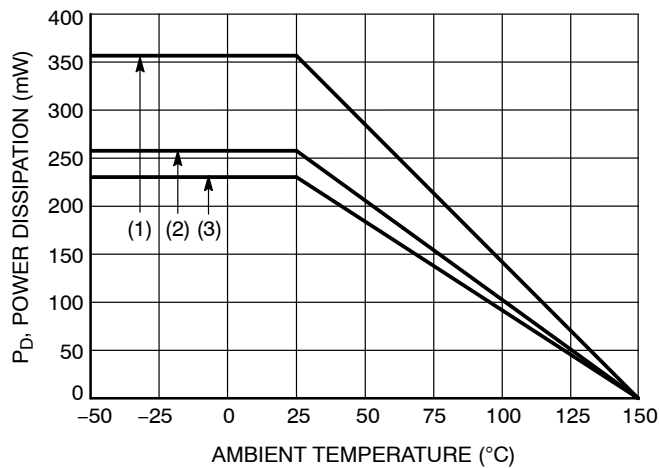


Figure 1. Derating Curve

- (1) SOT-363; 1.0 x 1.0 inch Pad
- (2) SOT-563; Minimum Pad
- (3) SOT-963; 100 mm<sup>2</sup>, 1 oz. copper trace



TYPICAL CHARACTERISTICS  
MUN5113DW1, NSBA144EDXV6

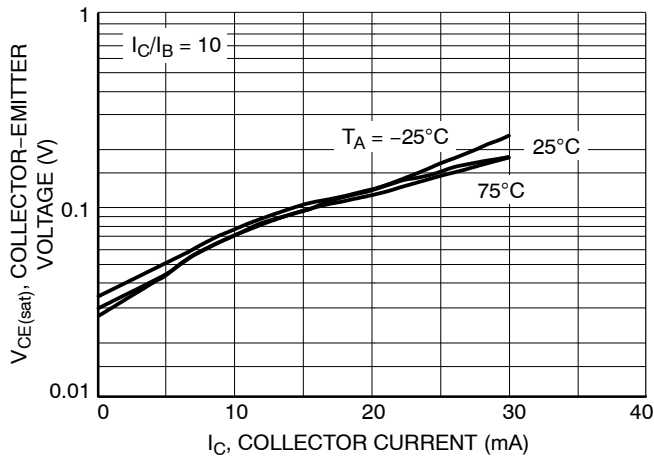


Figure 2.  $V_{CE(sat)}$  vs.  $I_C$

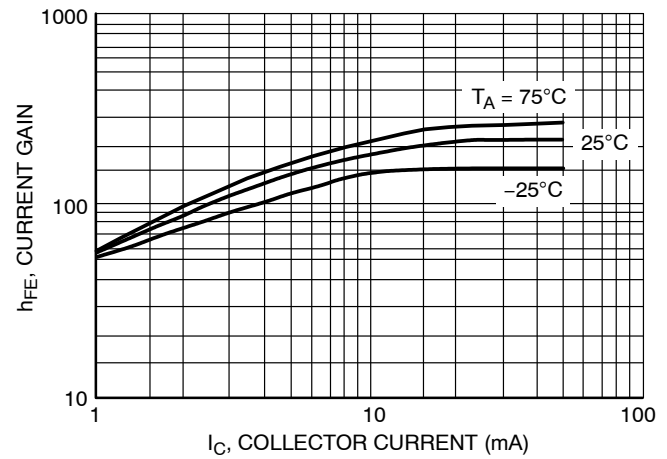


Figure 3. DC Current Gain

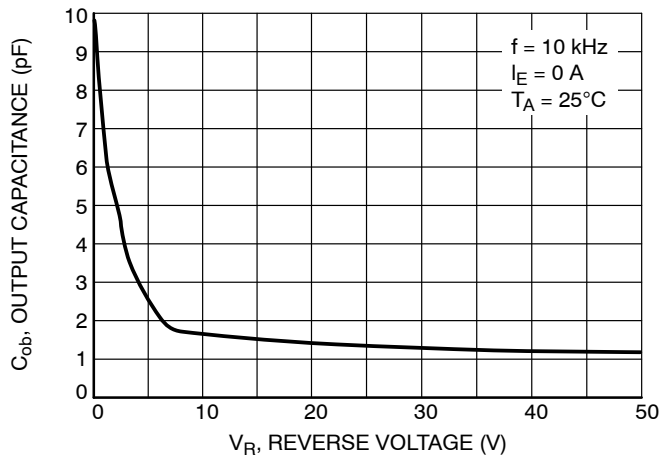


Figure 4. Output Capacitance

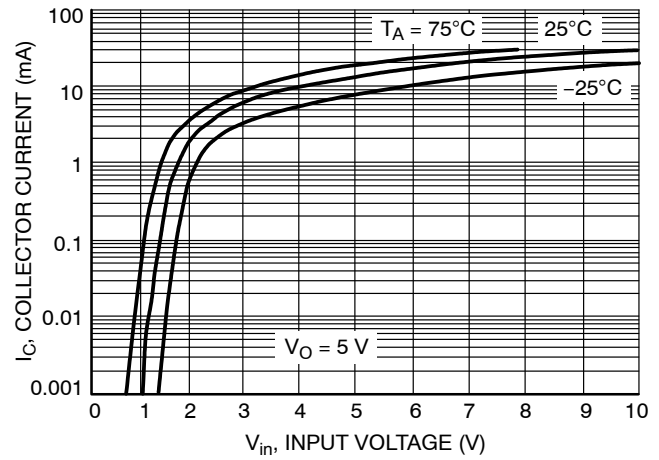


Figure 5. Output Current vs. Input Voltage

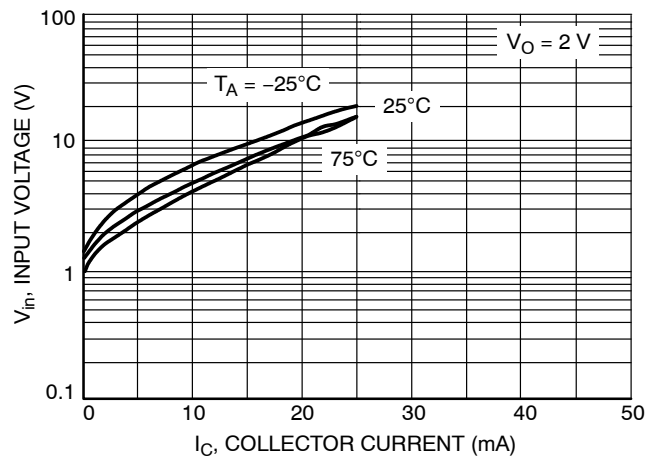


Figure 6. Input Voltage vs. Output Current

TYPICAL CHARACTERISTICS  
NSBA144EDP6

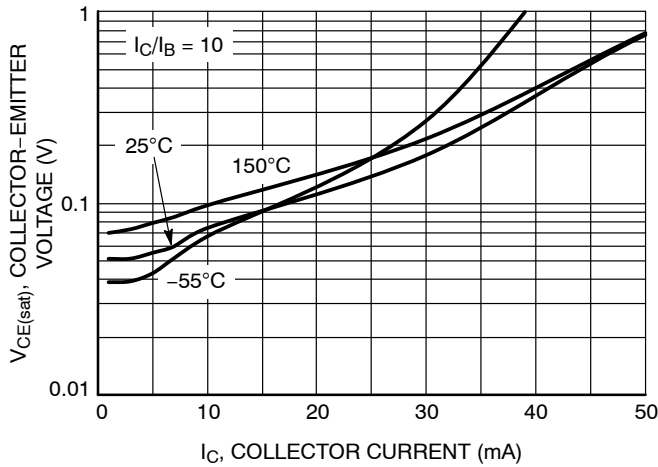


Figure 7.  $V_{CE(sat)}$  vs.  $I_C$

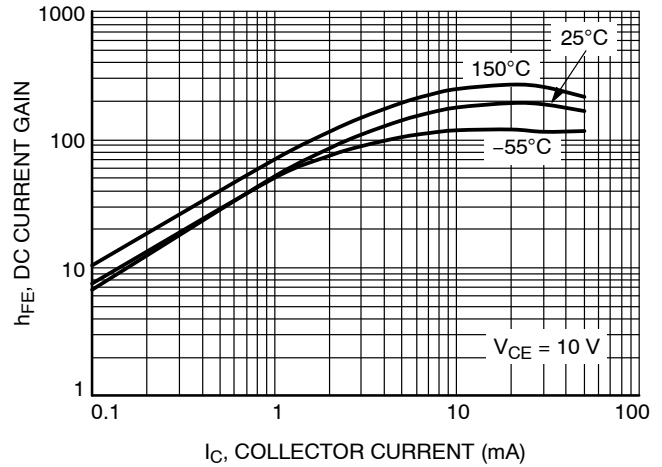


Figure 8. DC Current Gain

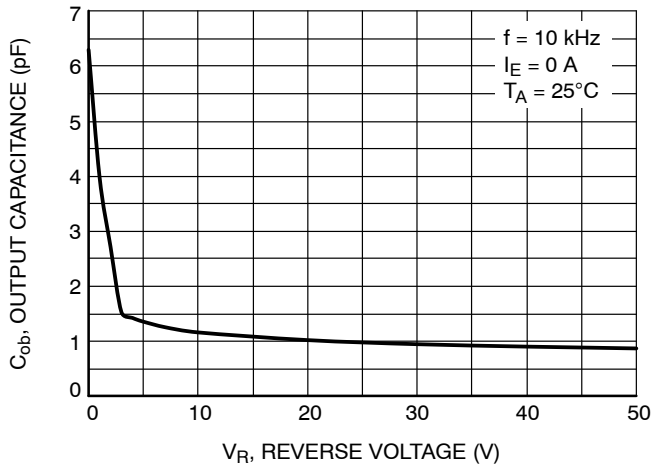


Figure 9. Output Capacitance

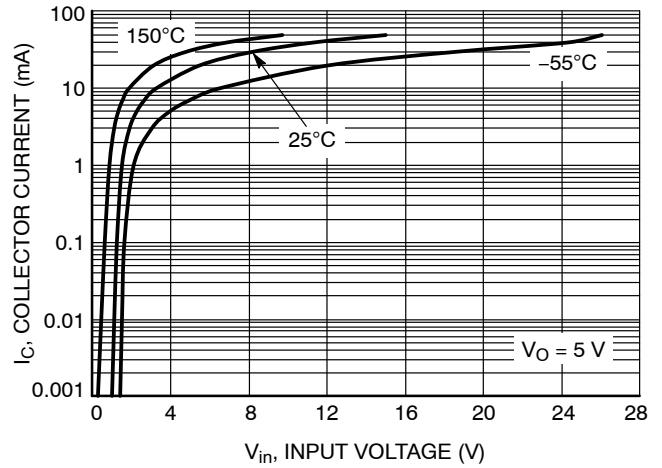


Figure 10. Output Current vs. Input Voltage

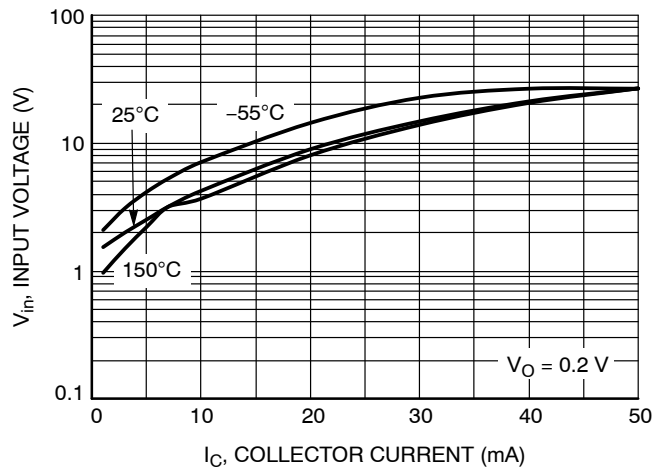


Figure 11. Input Voltage vs. Output Current

## MUN5113DW1, NSBA144EDXV6, NSBA144EDP6

### ORDERING INFORMATION

| Device                            | Package | Shipping <sup>†</sup> |
|-----------------------------------|---------|-----------------------|
| MUN5113DW1T1G,<br>SMUN5113DW1T1G* | SOT-363 | 3,000 / Tape & Reel   |
| NSVMUN5113DW1T3G*                 | SOT-363 | 10,000 / Tape & Reel  |
| NSBA144EDXV6T1G                   | SOT-563 | 4,000 / Tape & Reel   |
| NSBA144EDP6T5G                    | SOT-963 | 8,000 / Tape & Reel   |

### DISCONTINUED (Note 7)

|                 |         |                     |
|-----------------|---------|---------------------|
| NSBA144EDXV6T5G | SOT-563 | 8,000 / Tape & Reel |
|-----------------|---------|---------------------|

<sup>†</sup>For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specifications Brochure, [BRD8011/D](#).

7. **DISCONTINUED:** This device is not recommended for new design. Please contact your **onsemi** representative for information. The most current information on this device may be available on [www.onsemi.com](http://www.onsemi.com).



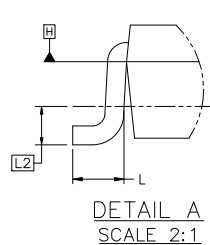
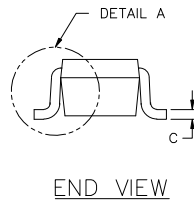
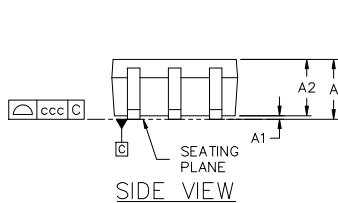
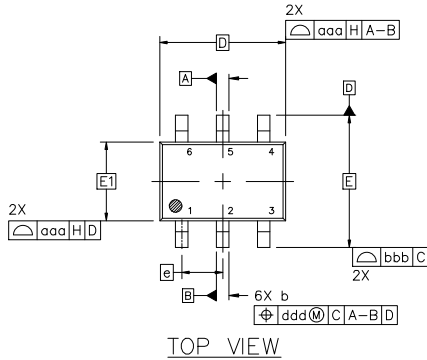


SC-88 2.00x1.25x0.90, 0.65P  
CASE 419B-02  
ISSUE Z

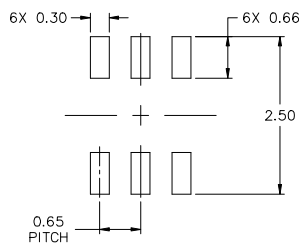
DATE 18 APR 2024

NOTES:

1. DIMENSIONING AND TOLERANCING CONFORM TO ASME Y14.5-2018.
2. ALL DIMENSION ARE IN MILLIMETERS.
3. DIMENSIONS D AND E1 DO NOT INCLUDE MOLD FLASH, PROTRUSIONS, OR GATE BURRS. MOLD FLASH, PROTRUSIONS, OR GATE BURRS SHALL NOT EXCEED 0.20 PER END.
4. DIMENSIONS D AND E1 AT THE OUTERMOST EXTREMES OF THE PLASTIC BODY AND DATUM H.
5. DATUMS A AND B ARE DETERMINED AT DATUM H.
6. DIMENSIONS b AND c APPLY TO THE FLAT SECTION OF THE LEAD BETWEEN 0.08 AND 0.15 FROM THE TIP.
7. DIMENSION b DOES NOT INCLUDE DAMBAR PROTRUSION. ALLOWABLE DAMBAR PROTRUSION SHALL BE 0.08 TOTAL IN EXCESS OF DIMENSION b AT MAXIMUM MATERIAL CONDITION. THE DAMBAR CANNOT BE LOCATED ON THE LOWER RADIUS OF THE FOOT.



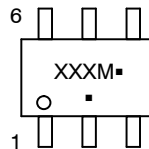
| DIM | MILLIMETERS |      |      |
|-----|-------------|------|------|
|     | MIN.        | NOM. | MAX. |
| A   | ---         | ---  | 1.10 |
| A1  | 0.00        | ---  | 0.10 |
| A2  | 0.70        | 0.90 | 1.00 |
| b   | 0.15        | 0.20 | 0.25 |
| c   | 0.08        | 0.15 | 0.22 |
| D   | 2.00 BSC    |      |      |
| E   | 2.10 BSC    |      |      |
| E1  | 1.25 BSC    |      |      |
| e   | 0.65 BSC    |      |      |
| L   | 0.26        | 0.36 | 0.46 |
| L2  | 0.15 BSC    |      |      |
| aaa | 0.15        |      |      |
| bbb | 0.30        |      |      |
| ccc | 0.10        |      |      |
| ddd | 0.10        |      |      |



RECOMMENDED MOUNTING FOOTPRINT\*

\* FOR ADDITIONAL INFORMATION ON OUR Pb-FREE STRATEGY AND SOLDERING DETAILS, PLEASE DOWNLOAD THE ONSEMI SOLDERING AND MOUNTING TECHNIQUES REFERENCE MANUAL, SOLDERRM/D.

GENERIC  
MARKING DIAGRAM\*



XXX = Specific Device Code  
M = Date Code\*  
▪ = Pb-Free Package

(Note: Microdot may be in either location)

\*Date Code orientation and/or position may vary depending upon manufacturing location.

\*This information is generic. Please refer to device data sheet for actual part marking. Pb-Free indicator, "G" or microdot "▪", may or may not be present. Some products may not follow the Generic Marking.

STYLES ON PAGE 2

|                  |                             |                                                                                                                                                                                  |
|------------------|-----------------------------|----------------------------------------------------------------------------------------------------------------------------------------------------------------------------------|
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| DESCRIPTION:     | SC-88 2.00x1.25x0.90, 0.65P | PAGE 1 OF 2                                                                                                                                                                      |

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SC-88 2.00x1.25x0.90, 0.65P  
CASE 419B-02  
ISSUE Z

DATE 18 APR 2024

|                                                                                                            |                                                                                                        |                                                                                                             |                                                                                                             |                                                                                                             |                                                                                                       |
|------------------------------------------------------------------------------------------------------------|--------------------------------------------------------------------------------------------------------|-------------------------------------------------------------------------------------------------------------|-------------------------------------------------------------------------------------------------------------|-------------------------------------------------------------------------------------------------------------|-------------------------------------------------------------------------------------------------------|
| STYLE 1:<br>PIN 1. EMITTER 2<br>2. BASE 2<br>3. COLLECTOR 1<br>4. EMITTER 1<br>5. BASE 1<br>6. COLLECTOR 2 | STYLE 2:<br>CANCELLED                                                                                  | STYLE 3:<br>CANCELLED                                                                                       | STYLE 4:<br>PIN 1. CATHODE<br>2. CATHODE<br>3. COLLECTOR<br>4. EMITTER<br>5. BASE<br>6. ANODE               | STYLE 5:<br>PIN 1. ANODE<br>2. ANODE<br>3. COLLECTOR<br>4. EMITTER<br>5. BASE<br>6. CATHODE                 | STYLE 6:<br>PIN 1. ANODE 2<br>2. N/C<br>3. CATHODE 1<br>4. ANODE 1<br>5. N/C<br>6. CATHODE 2          |
| STYLE 7:<br>PIN 1. SOURCE 2<br>2. DRAIN 2<br>3. GATE 1<br>4. SOURCE 1<br>5. DRAIN 1<br>6. GATE 2           | STYLE 8:<br>CANCELLED                                                                                  | STYLE 9:<br>PIN 1. EMITTER 2<br>2. EMITTER 1<br>3. COLLECTOR 1<br>4. BASE 1<br>5. BASE 2<br>6. COLLECTOR 2  | STYLE 10:<br>PIN 1. SOURCE 2<br>2. SOURCE 1<br>3. GATE 1<br>4. DRAIN 1<br>5. DRAIN 2<br>6. GATE 2           | STYLE 11:<br>PIN 1. CATHODE 2<br>2. CATHODE 2<br>3. ANODE 1<br>4. CATHODE 1<br>5. CATHODE 1<br>6. ANODE 2   | STYLE 12:<br>PIN 1. ANODE 2<br>2. ANODE 2<br>3. CATHODE 1<br>4. ANODE 1<br>5. ANODE 1<br>6. CATHODE 2 |
| STYLE 13:<br>PIN 1. ANODE<br>2. N/C<br>3. COLLECTOR<br>4. EMITTER<br>5. BASE<br>6. CATHODE                 | STYLE 14:<br>PIN 1. VREF<br>2. GND<br>3. GND<br>4. IOUT<br>5. VEN<br>6. VCC                            | STYLE 15:<br>PIN 1. ANODE 1<br>2. ANODE 2<br>3. ANODE 3<br>4. CATHODE 3<br>5. CATHODE 2<br>6. CATHODE 1     | STYLE 16:<br>PIN 1. BASE 1<br>2. EMITTER 2<br>3. COLLECTOR 2<br>4. BASE 2<br>5. EMITTER 1<br>6. COLLECTOR 1 | STYLE 17:<br>PIN 1. BASE 1<br>2. EMITTER 1<br>3. COLLECTOR 2<br>4. BASE 2<br>5. EMITTER 2<br>6. COLLECTOR 1 | STYLE 18:<br>PIN 1. VIN1<br>2. VCC<br>3. VOUT2<br>4. VIN2<br>5. GND<br>6. VOUT1                       |
| STYLE 19:<br>PIN 1. I OUT<br>2. GND<br>3. GND<br>4. V CC<br>5. V EN<br>6. V REF                            | STYLE 20:<br>PIN 1. COLLECTOR<br>2. COLLECTOR<br>3. BASE<br>4. EMITTER<br>5. COLLECTOR<br>6. COLLECTOR | STYLE 21:<br>PIN 1. ANODE 1<br>2. N/C<br>3. ANODE 2<br>4. CATHODE 2<br>5. N/C<br>6. CATHODE 1               | STYLE 22:<br>PIN 1. D1 (i)<br>2. GND<br>3. D2 (i)<br>4. D2 (c)<br>5. VBUS<br>6. D1 (c)                      | STYLE 23:<br>PIN 1. Vn<br>2. CH1<br>3. Vp<br>4. N/C<br>5. CH2<br>6. N/C                                     | STYLE 24:<br>PIN 1. CATHODE<br>2. ANODE<br>3. CATHODE<br>4. CATHODE<br>5. CATHODE<br>6. CATHODE       |
| STYLE 25:<br>PIN 1. BASE 1<br>2. CATHODE<br>3. COLLECTOR 2<br>4. BASE 2<br>5. EMITTER<br>6. COLLECTOR 1    | STYLE 26:<br>PIN 1. SOURCE 1<br>2. GATE 1<br>3. DRAIN 2<br>4. SOURCE 2<br>5. GATE 2<br>6. DRAIN 1      | STYLE 27:<br>PIN 1. BASE 2<br>2. BASE 1<br>3. COLLECTOR 1<br>4. EMITTER 1<br>5. EMITTER 2<br>6. COLLECTOR 2 | STYLE 28:<br>PIN 1. DRAIN<br>2. DRAIN<br>3. GATE<br>4. SOURCE<br>5. DRAIN<br>6. DRAIN                       | STYLE 29:<br>PIN 1. ANODE<br>2. ANODE<br>3. COLLECTOR<br>4. EMITTER<br>5. BASE/ANODE<br>6. CATHODE          | STYLE 30:<br>PIN 1. SOURCE 1<br>2. DRAIN 2<br>3. DRAIN 2<br>4. SOURCE 2<br>5. GATE 1<br>6. DRAIN 1    |

Note: Please refer to datasheet for style callout. If style type is not called out in the datasheet refer to the device datasheet pinout or pin assignment.

|                  |                             |                                                                                                                                                                                     |
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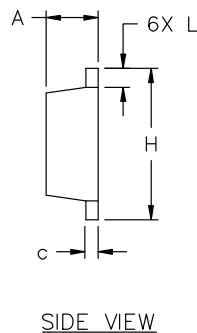
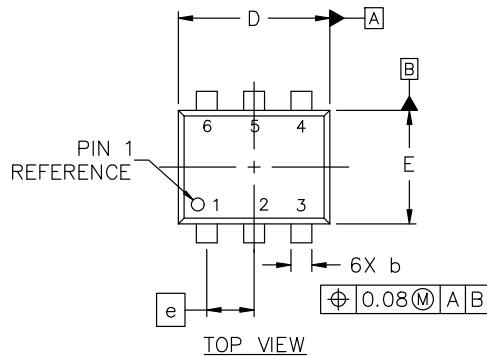


**SOT-563-6 1.60x1.20x0.55, 0.50P**  
**CASE 463A**  
**ISSUE J**

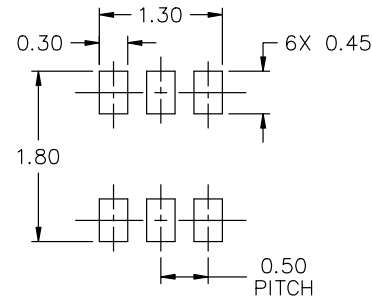
DATE 15 FEB 2024

NOTES:

1. DIMENSIONING AND TOLERANCING CONFORM TO ASME Y14.5-2018.
2. ALL DIMENSION ARE IN MILLIMETERS.
3. MAXIMUM LEAD THICKNESS INCLUDES LEAD FINISH THICKNESS. MINIMUM LEAD THICKNESS IS THE MINIMUM THICKNESS OF BASE MATERIAL.



| DIM | MILLIMETERS |      |      |
|-----|-------------|------|------|
|     | MIN.        | NOM. | MAX. |
| A   | 0.50        | 0.55 | 0.60 |
| b   | 0.17        | 0.22 | 0.27 |
| c   | 0.08        | 0.13 | 0.18 |
| D   | 1.50        | 1.60 | 1.70 |
| E   | 1.10        | 1.20 | 1.30 |
| e   | 0.50 BSC    |      |      |
| H   | 1.50        | 1.60 | 1.70 |
| L   | 0.10        | 0.20 | 0.30 |



STYLE 1:  
PIN 1. EMITTER 1  
2. BASE 1  
3. COLLECTOR 2  
4. EMITTER 2  
5. BASE 2  
6. COLLECTOR 1

STYLE 2:  
PIN 1. EMITTER 1  
2. EMITTER 2  
3. BASE 2  
4. COLLECTOR 2  
5. BASE 1  
6. COLLECTOR 1

STYLE 3:  
PIN 1. CATHODE 1  
2. CATHODE 1  
3. ANODE/ANODE 2  
4. CATHODE 2  
5. CATHODE 2  
6. ANODE/ANODE 1

STYLE 4:  
PIN 1. COLLECTOR  
2. COLLECTOR  
3. BASE  
4. EMITTER  
5. COLLECTOR  
6. COLLECTOR

STYLE 5:  
PIN 1. CATHODE  
2. CATHODE  
3. ANODE  
4. ANODE  
5. CATHODE  
6. CATHODE

STYLE 6:  
PIN 1. CATHODE  
2. ANODE  
3. CATHODE  
4. CATHODE  
5. CATHODE  
6. CATHODE

STYLE 7:  
PIN 1. CATHODE  
2. ANODE  
3. CATHODE  
4. CATHODE  
5. ANODE  
6. CATHODE

STYLE 8:  
PIN 1. DRAIN  
2. DRAIN  
3. GATE  
4. SOURCE  
5. DRAIN  
6. DRAIN

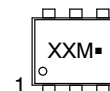
STYLE 9:  
PIN 1. SOURCE 1  
2. GATE 1  
3. DRAIN 2  
4. SOURCE 2  
5. GATE 2  
6. DRAIN 1

STYLE 10:  
PIN 1. CATHODE 1  
2. N/C  
3. CATHODE 2  
4. ANODE 2  
5. N/C  
6. ANODE 1

STYLE 11:  
PIN 1. EMITTER 2  
2. BASE 2  
3. COLLECTOR 1  
4. EMITTER 1  
5. BASE 1  
6. COLLECTOR 2

\* FOR ADDITIONAL INFORMATION ON OUR Pb-FREE STRATEGY AND SOLDERING DETAILS, PLEASE DOWNLOAD THE ON SEMICONDUCTOR SOLDERING AND MOUNTING TECHNIQUES REFERENCE MANUAL, SOLDERM/D.

**GENERIC  
MARKING DIAGRAM\***

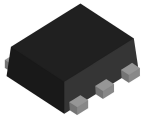


XX = Specific Device Code  
M = Month Code  
▪ = Pb-Free Package

\*This information is generic. Please refer to device data sheet for actual part marking. Pb-Free indicator, "G" or microdot "▪", may or may not be present. Some products may not follow the Generic Marking.

|                         |                                        |                                                                                                                                                                                  |
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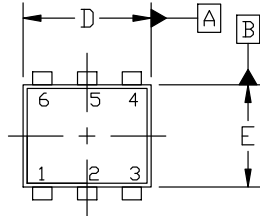


**SOT-963 1.00x1.00x0.37, 0.35P**  
**CASE 527AD**  
**ISSUE F**

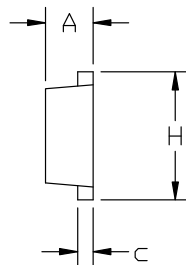
DATE 20 FEB 2024

NOTES:

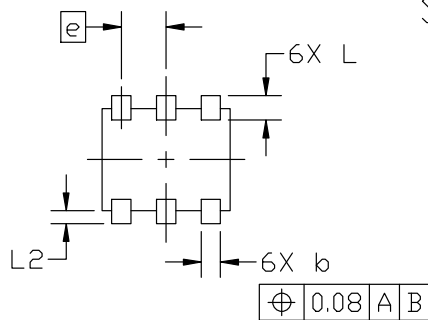
1. DIMENSIONING AND TOLERANCING PER ASME Y14.5M, 2018.
2. CONTROLLING DIMENSION: MILLIMETERS.
3. MAXIMUM LEAD THICKNESS INCLUDES LEAD FINISH THICKNESS. MINIMUM LEAD THICKNESS IS THE MINIMUM THICKNESS OF BASE MATERIAL.
4. DIMENSIONS D AND E DO NOT INCLUDE MOLD FLASH, PROTRUSIONS, OR GATE BURRS.



TOP VIEW

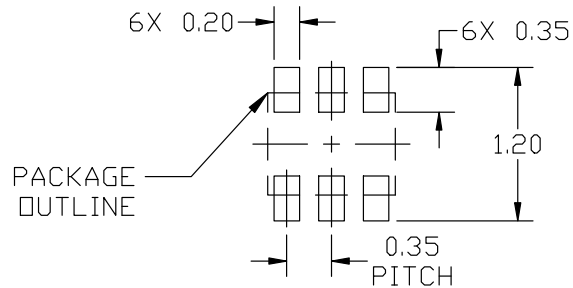


SIDE VIEW



BOTTOM VIEW

| DIM | MILLIMETERS |      |      |
|-----|-------------|------|------|
|     | MIN.        | NOM. | MAX. |
| A   | 0.34        | 0.37 | 0.40 |
| b   | 0.10        | 0.15 | 0.20 |
| c   | 0.07        | 0.12 | 0.17 |
| D   | 0.95        | 1.00 | 1.05 |
| E   | 0.75        | 0.80 | 0.85 |
| e   | 0.35 BSC    |      |      |
| H   | 0.95        | 1.00 | 1.05 |
| L   | 0.19 REF    |      |      |
| L2  | 0.05        | 0.10 | 0.15 |



RECOMMENDED MOUNTING  
FOOTPRINT

\*For additional information on our Pb-Free strategy and soldering details, please download the ON Semiconductor Soldering and Mounting Techniques Reference manual, SOLDERRM/D.

STYLE 1:

- PIN 1. EMITTER 1  
2. BASE 1  
3. COLLECTOR 2  
4. EMITTER 2  
5. BASE 2  
6. COLLECTOR 1

STYLE 2:

- PIN 1. EMITTER 1  
2. EMITTER 2  
3. BASE 2  
4. COLLECTOR 2  
5. BASE 1  
6. COLLECTOR 1

STYLE 3:

- PIN 1. CATHODE 1  
2. CATHODE 1  
3. ANODE/ANODE 2  
4. CATHODE 2  
5. CATHODE 2  
6. ANODE/ANODE 1

STYLE 4:

- PIN 1. COLLECTOR  
2. COLLECTOR  
3. BASE  
4. EMITTER  
5. COLLECTOR  
6. COLLECTOR

STYLE 5:

- PIN 1. CATHODE  
2. CATHODE  
3. ANODE  
4. ANODE  
5. CATHODE  
6. CATHODE

STYLE 6:

- PIN 1. CATHODE  
2. ANODE  
3. CATHODE  
4. CATHODE  
5. CATHODE  
6. CATHODE

STYLE 7:

- PIN 1. CATHODE  
2. ANODE  
3. CATHODE  
4. CATHODE  
5. ANODE  
6. CATHODE

STYLE 8:

- PIN 1. DRAIN  
2. DRAIN  
3. GATE  
4. SOURCE  
5. DRAIN  
6. DRAIN

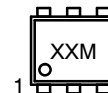
STYLE 9:

- PIN 1. SOURCE 1  
2. GATE 1  
3. DRAIN 2  
4. SOURCE 2  
5. GATE 2  
6. DRAIN 1

STYLE 10:

- PIN 1. CATHODE 1  
2. N/C  
3. CATHODE 2  
4. ANODE 2  
5. N/C  
6. ANODE 1

**GENERIC  
MARKING DIAGRAM\***



XX = Specific Device Code  
M = Month Code

\*This information is generic. Please refer to device data sheet for actual part marking. Pb-Free indicator, "G" or microdot "•", may or may not be present. Some products may not follow the Generic Marking.

|                         |                                      |                                                                                                                                                                                  |
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